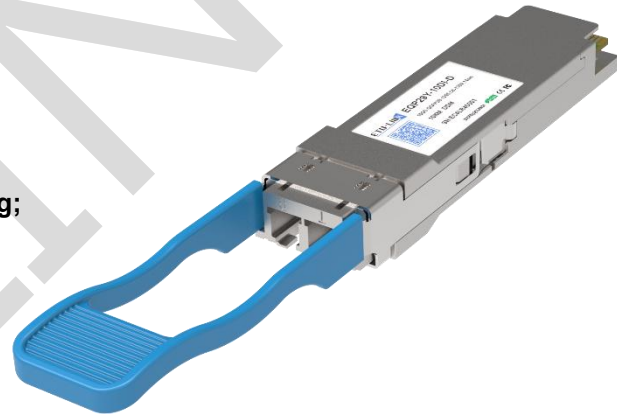


EQP29Y-10D(I)-D

QSFP28 100Gb/s Single-mode 10km DDM Transceiver

PRODUCT FEATURES

- Support line rates from 103.125 Gbps to 111.81 Gbps;
- Transmission data rate up to 25.78 and 27.95 Gbps (NRZ) per channel;
- Up to 10km transmission on single mode fiber;
- High speed I/O electrical interface (CAUI-4);
- I2C interface with integrated Digital Diagnostic monitoring;
- QSFP28 MSA package with duplex LC connector;
- Single +3.3V power supply; Dissipation:
 - Commercial(0~70): < 4W
 - Industrial(-40~85): < 5W
- Complies with EU Directive 2015/863/EU;



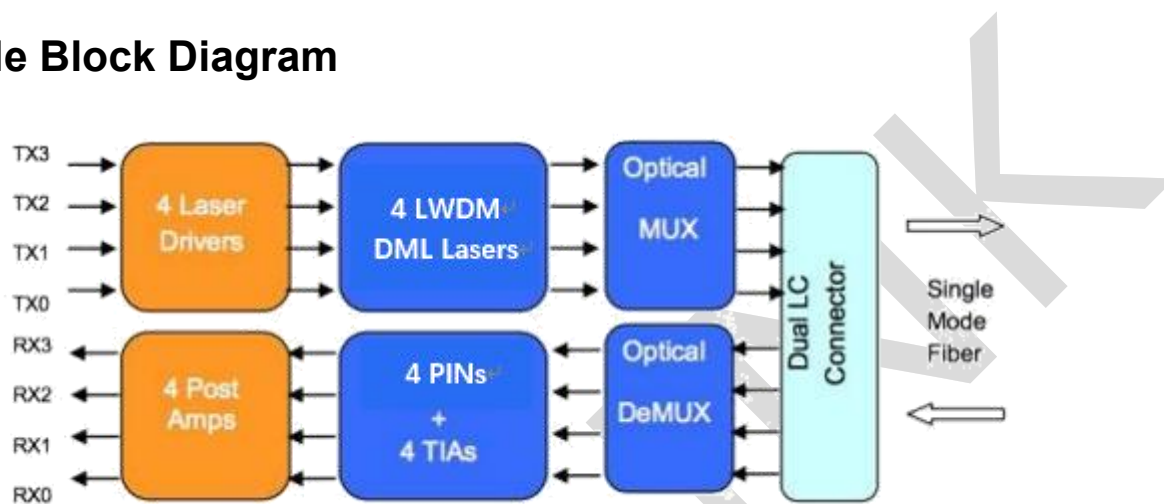
APPLICATIONS

- 100GBASE-LR4 Ethernet
- 100G Datacom & Telecom connections
- ITU-T OTU4

DESCRIPTIONS

100G QSFP LR4 Transceiver is designed for 10km optical communication applications. This module contains 4-lane optical transmitter, 4-lane optical receiver and module management block including 2 wire serial inter-face. The optical signals are multiplexed to a single-mode fiber through an industry standard LC connector.

Module Block Diagram



Ordering Information

Part No.	Data Rate(optical)	Laser	Fiber Type	Distance	Optical Interface	Temp	DDMI	Latch Color
EQP29Y-10D-D	103.125/111.81	DML	SMF	10km	LC	0~70	Yes	Blue
EQP29Y-10DI-D	103.125	DML	SMF	10km	LC	-40~85	Yes	Blue

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit
Storage Temperature	TS	-40	+85	°C
Maximum Supply Voltage	VCC	-0.5	3.6	V
Operating Relative Humidity	RH		85	%

Recommended Operating Conditions

Parameter	Symbol	Min.	Typical	Max.	Unit	Notes
Operating Case Temperature	Top	0		+70	°C	EQP29Y-10D-D
		-40		+85		EQP29Y-10DI-D

Power Supply Voltage	V _{CC}	3.13	3.3	3.47	V	
Power Supply Current	I _{CC}			1.21	A	EQP29Y-10D-D
				1.51	A	EQP29Y-10DI-D
Maximum Power Dissipation	P _D			4	W	EQP29Y-10D-D
				5		EQP29Y-10DI-D
Aggregate Bit Rate	BR _{AVE}		103.125 /111.81		Gb/s	
Lane Bit Rate	BR _{LANE}		25.7812 5/27.95		Gb/s	
Transmission Distance	TD			10	km	
Coupled fiber	Single mode fiber					9/125um SMF

Electrical Characteristics

Parameter	Symbol	Min.	Typical	Max.	Unit	Notes
Transmitter (Module Input)						
Data Rate, each lane			25.78125		Gbps	
Differential Voltage pk-pk	V _{pp}			900	mV	1
Common Mode Voltage	V _{cm}	-350		2850	mV	
Transition time	Trise/Tf _{all}	10			ps	2
Receiver (Module Output)						
Data Rate, each lane			25.78125		Gbps	
Common Mode Noise, RMS	V _{rms}			17.5	mV	
Differential output voltage swing	V _{out, pp}			900	mV	
Eye width	EW ₁₅	0.57			UI	
Eye height	EH ₁₅	228			mV	
Differential Termination Resistance Mismatch				10	%	1
Transition time	Trise/Tf _{all}	12			ps	

Optical and Characteristics

Specifications for 100Gbase-LR4

Parameter	Symbol	Min.	Typical	Max.	Unit	Notes
Transmitter						
Signaling Speed per Lane			25.78125		Gbps	
Lane Wavelength	L0	1294.53	1295.56	1296.59	nm	
	L1	1299.02	1300.05	1301.09	nm	
	L2	1303.54	1304.58	1305.63	nm	

	L3	1308.09	1309.14	1310.19	nm	
Total Average Launch Power	P _T			10.5	dBm	1
Average Launch Power per Lane,	P _{avg}	-4.3		4.5	dBm	1
OMA, each Lane	P _{OMA}	-1.3		4.5	dBm	1
Difference in launch power between any two lanes(Average and OMA) between any Two Lanes (OMA)	P _{tx,diff}			3	dB	
Average Output Power (Laser Turn off)	P _{off}			-30	dBm	
Side Mode Suppression Ratio	SMSR	30			dB	
Extinction Ratio	ER	4			dB	
RIN ₂₀ OMA	RIN			-130	dB/Hz	
Optical Return Loss Tolerance	TOL			20	dB	
Transmitter Reflectance	R _T			-12	dB	
Optical Eye Mask	{0.25,0.4, 0.45, 0.25, 0.28, 0.4}				%	2
Receiver						
Signaling rate, each lane			25.78125		Gbps	
Center Wavelength Lane 0	λ0	1294.53	1295.56	1296.59	nm	
Center Wavelength Lane 1	λ1	1299.02	1300.05	1301.09	nm	
Center Wavelength Lane 2	λ2	1303.54	1304.58	1305.63	nm	
Center Wavelength Lane 3	λ3	1308.09	1309.14	1310.19	nm	
Damage threshold , each lane	P _{damage}	5.5			dBm	
Average Receive Power, each lane		-10.6		4.5	dBm	
Receiver Sensitivity (OMA) per Lane	SEN			-8.6	dBm	3
Los Assert	LosA	-30			dBm	
Los De-assert	LosDA			-12	dBm	
Los Hysteresis	LosH	0.5			dB	

Specifications for OUT4 4I1-9D1F

Parameter	Symbol	Min.	Typical	Max.	Unit	Notes
Transmitter						
Signaling Speed per Lane			27.9525		Gbps	
Lane Wavelength	L0	1294.53	1295.56	1296.59	nm	
	L1	1299.02	1300.05	1301.09	nm	
	L2	1303.54	1304.58	1305.63	nm	
	L3	1308.09	1309.14	1310.19	nm	
Total Average Launch Power	P_T			10	dBm	1
Average Launch Power per Lane,	P_{avg}	-0.6		4	dBm	1
Difference in launch power	$P_{tx,diff}$			3	dB	

between any two lanes(Average and OMA) between any Two Lanes (OMA)						
Average Output Power (Laser Turn off)	P _{off}			-30	dBm	
Side Mode Suppression Ratio	SMSR	30			dB	
Extinction Ratio	ER	4		7	dB	
Optical Eye Mask	{0.25,0.4, 0.45, 0.25, 0.28, 0.4}				%	2
Receiver						
Signaling rate, each lane			27.9525		Gbps	
Center Wavelength Lane 0	λ0	1294.53	1295.56	1296.59	nm	
Center Wavelength Lane 1	λ1	1299.02	1300.05	1301.09	nm	
Center Wavelength Lane 2	λ2	1303.54	1304.58	1305.63	nm	
Center Wavelength Lane 3	λ3	1308.09	1309.14	1310.19	nm	
Damage threshold , each lane	Pdamage	5.5			dBm	
Average Receive Power, each lane		-6.9		4	dBm	
Receiver sensitivity, each lane	SEN			-8.4	dBm	4
Los Assert	LosA	-30			dBm	
Los De-assert	LosDA			-12	dBm	
Los Hysteresis	LosH	0.5			dB	

Note:

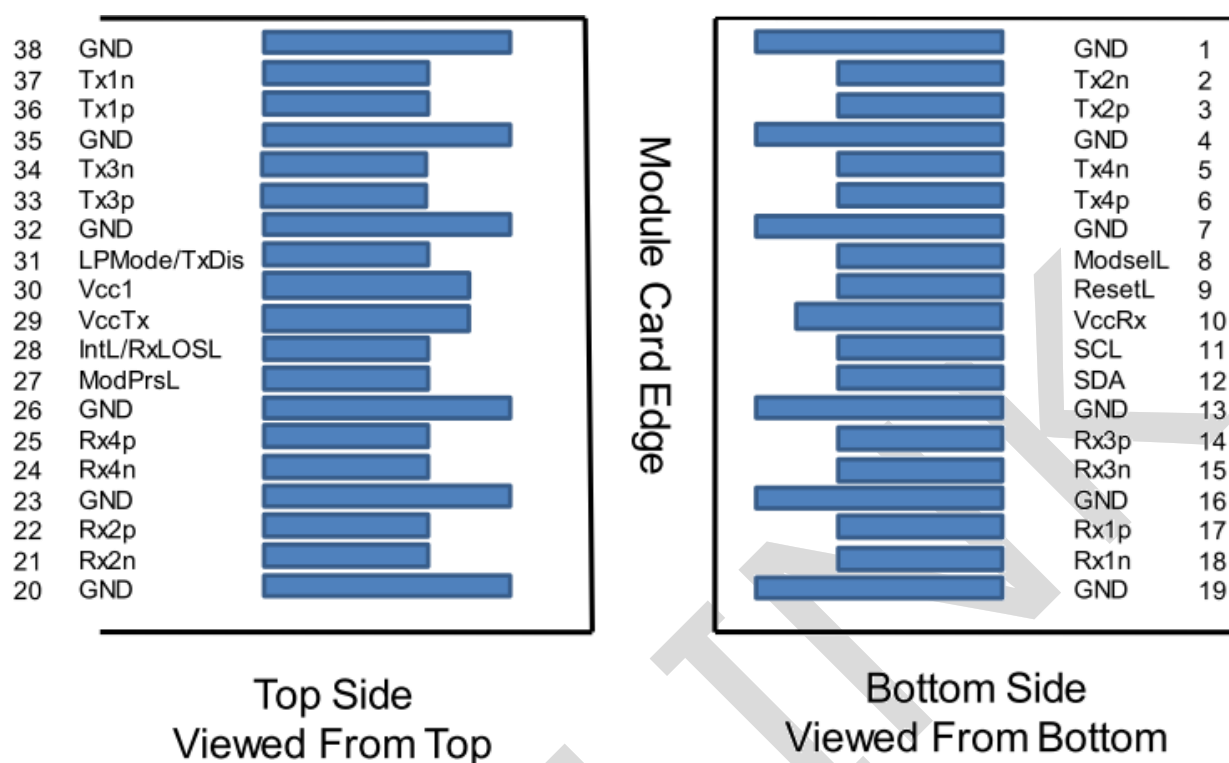
Note:

1. The optical power is launched into SMF.
2. Measured with a PRBS 231-1 test pattern @25.78125, Hit ratio $\leq$ 5E-5.
3. Measured with a PRBS 231-1 test pattern @25.78125 Gb/s, BER $\leq$ 1E-12.
4. The BER for these application codes is required to be met only after the error correction (if used) has been applied. The BER at the input of the FEC decoder can therefore be significantly higher than 10⁻¹²

Digital Diagnostics

Parameter	Range	Unit	Accuracy	Calibration
Temperature	-40 to +85	°C	$\pm 3^\circ\text{C}$	Internal / External
Voltage	3.0 to 3.6	V	$\pm 3\%$	Internal / External
Bias Current	30 to 100	mA	$\pm 10\%$	Internal / External
TX Power	-4.3 to 4.5	dBm	$\pm 3\text{dB}$	Internal / External
RX Power	-10.6 to 4.5	dBm	$\pm 3\text{dB}$	Internal / External

Pin Diagram



Pin Definitions

PIN	Logic	Symbol	Description	Plug Seq.	Notes
1		GND	Ground	1	1
2	CML-I	Tx2n	Transmitter Inverted Data Input	3	
3	CML-I	Tx2p	Transmitter Non-Inverted Data output	3	
4		GND	Ground	1	1
5	CML-I	Tx4n	Transmitter Inverted Data Input	3	
6	CML-I	Tx4p	Transmitter Non-Inverted Data output	3	
7		GND	Ground	1	1
8	LVTLL-I	ModSelL	Module Select	3	
9	LVTLL-I	ResetL	Module Reset	3	
10		VccRx	+ 3.3V Power Supply Receiver	2	2
11	LVC MOS-I/O	SCL	2-Wire Serial Interface Clock	3	
12	LVC MOS-I/O	SDA	2-Wire Serial Interface Data	3	
13		GND	Ground	1	
14	CML-O	Rx3p	Receiver Non-Inverted Data Output	3	
15	CML-O	Rx3n	Receiver Inverted Data Output	3	
16		GND	Ground	1	1

17	CML-O	Rx1p	Receiver Non-Inverted Data Output	3	
18	CML-O	Rx1n	Receiver Inverted Data Output	3	
19		GND	Ground	1	1
20		GND	Ground	1	1
21	CML-O	Rx2n	Receiver Inverted Data Output	3	
22	CML-O	Rx2p	Receiver Non-Inverted Data Output	3	
23		GND	Ground	1	1
24	CML-O	Rx4n	Receiver Inverted Data Output	3	1
25	CML-O	Rx4p	Receiver Non-Inverted Data Output	3	
26		GND	Ground	1	1
27	LVTTL-O	ModPrsL	Module Present	3	
28	LVTTL-O	IntL/Rx_LOS	Interrupt/Rx_LOS	3	
29		VccTx	+3.3 V Power Supply transmitter	2	2
30		Vcc1	+3.3 V Power Supply	2	2
31	LVTTL-I	LPMODE/TxDIS	Low Power Mode/Tx_Disable	3	
32		GND	Ground	1	1
33	CML-I	Tx3p	Transmitter Non-Inverted Data Input	3	
34	CML-I	Tx3n	Transmitter Inverted Data Output	3	
35		GND	Ground	1	1
36	CML-I	Tx1p	Transmitter Non-Inverted Data Input	3	
37	CML-I	Tx1n	Transmitter Inverted Data Output	3	
38		GND	Ground	1	1

Notes:

1. GND is the symbol for signal and supply (power) common for the QSFP28 module. All are common within the QSFP28 module and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal-common ground plane.
2. Vcc Rx, Vcc1 and Vcc Tx are the receiver and transmitter power supplies and shall be applied concurrently. Requirements defined for the host side of the Host Edge Card Connector are listed in MSA. The connector pins are each rated for a maximum current of 1000 mA.

Recommended Interface Circuit

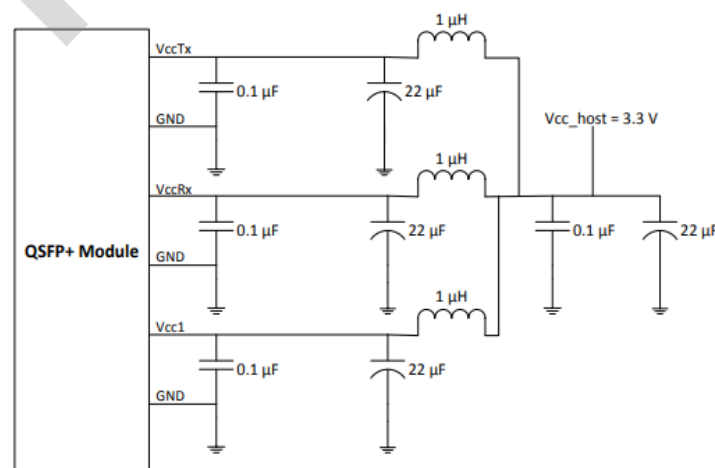
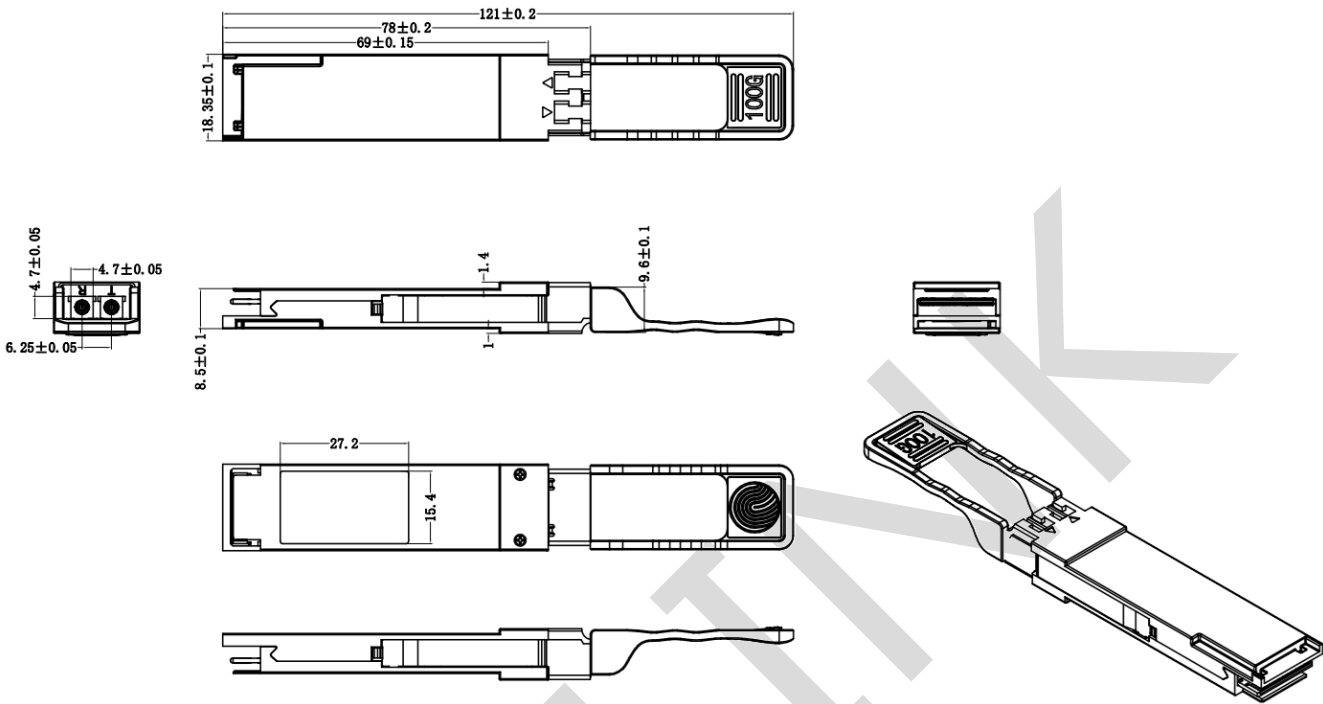


FIGURE 5-4 RECOMMENDED HOST BOARD POWER SUPPLY FILTERING

Mechanical Diagram



Revision History

Version No.	Date	Description
1.0	Aug 21, 2022	Preliminary datasheet
1.1	July 20, 2024	Format change
1.2	Oct 08, 2024	Add OUT4 specifications

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